

## Solid State Devices, Inc.

14701 Firestone Blvd \* La Mirada, Ca 90638 Phone: (562) 404-4474 \* Fax: (562) 404-1773 ssdi@ssdi-power.com \* www.ssdi-power.com

### **DESIGNER'S DATA SHEET**

### Part Number / Ordering Information 1/ SPD5 L Screening<sup>2/</sup> = None TX = TX Level TXV = TXV Level S = S Level **Package** = Axial Leaded SMS = Surface Mount Square Tab Voltage 02 = 200 V03 = 300 V04 = 400 V05 = 500 V06 = 600V

## SPD502-SPD506 and SPD502SMS - SPD506SMS

5 AMP
200–600 Volts
40 nsec
HYPER FAST RECTIFIER

#### Features:

- Hyper Fast Recovery: 40 nsec Max.
- PIV to 600 Volts
- Low Forward Voltage Drop
- Void Free Construction
- Hermetically Sealed Surface Mount Package
- For High Efficiency Applications
- Single Chip Construction
- TX, TXV, and S-Level Screening Available<sup>2/</sup>

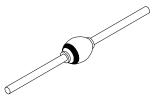
Maximum Ratings		Symbol	Value	Units	
Peak Repetitive Reverse and DC Blocking Voltage		SPD502 SPD503 SPD504 SPD505 SPD506	$egin{array}{c} egin{array}{c} egin{array}$	200 300 400 500 600	Volts
Average Rectified Forward Current (Resistive Load, 60 Hz, Sine Wave, T <sub>A</sub> = 25°C)		Io	5	Amps	
Surge Current (8.3 ms Pulse, Half Sine Wave Superimposed on Io, Allow Junction to Reach Equilibrium between Pulses, $T_A = 25^{\circ}C$ )		${ m I_{FSM}}$	100	Amps	
Operating & Storage Temperature		Top & Tstg	-65 to +175	°C	
Maximum Thermal Resistance		ion to Lead, L=3/8" Junction to End Tab	$egin{array}{c} \mathbf{R}_{oldsymbol{ heta}\mathrm{JL}} \ \mathbf{R}_{oldsymbol{ heta}\mathrm{JE}} \end{array}$	15 10	°C/W

Notes:

 $\underline{1}/$  For Ordering Information, Price, Operating Curves, and Availability – Contact Factory.

2/ Screening Based on MIL-PRF-19500. Screening Flows Available on Request.







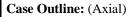


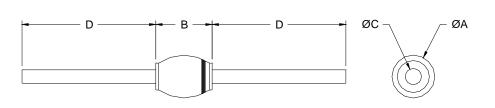
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# SPD502-SPD506 and SPD502SMS - SPD506SMS

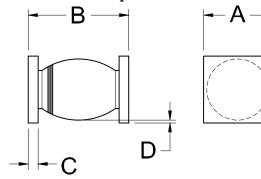
Electrical Characteristics	Symbol	Max	Units
Instantaneous Forward Voltage Drop $(I_F = 5 \text{ Adc}, T_A = 25^{\circ}\text{C}, 300 \mu\text{s pulse})$	$ m V_{F}$	1.6	Vdc
<b>Instantaneous Forward Voltage Drop</b> (I <sub>F</sub> = 5Adc, T <sub>A</sub> = -55°C, 300 µs pulse)	$ m V_F$	1.75	Vdc
Reverse Leakage Current (Rated $V_R$ , $T_A = 25$ °C, 300 $\mu$ s pulse minimum)	$I_R$	10	μА
Reverse Leakage Current (Rated $V_R$ , $T_A = 100$ °C, 300 µs pulse minimum)	$I_R$	1	mA
<b>Junction Capacitance</b> (V <sub>R</sub> = 10 Vdc, T <sub>A</sub> = 25°C, f = 1MHz)	C <sub>J</sub>	50	pF
Reverse Recovery Time $(I_F = 500 \text{ mA}, I_R = 1A, I_{RR} = 0.25A, T_A = 25^{\circ}\text{C})$	t <sub>rr</sub>	40	nsec





DIMENSIONS				
DIM	MIN	MAX		
A	.140"	.170"		
В	.170"	.230"		
C	.047"	.053"		
D	1.00"			

### Case Outline: Surface Mount Square Tab



DIMENSIONS				
DIM	MIN	MAX		
A	.172"	.180"		
В	.220"	.270"		
C	.020"	.035"		
D	.002"			